NSN 5961-01-066-0422

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Inclosure Material: Metal all transistor **Overall Length:** 0.200 inches all transistor and 0.260 inches all transistor **Terminal Length:** 0.500 inches all transistor **Overall Diameter:** 0.290 inches all transistor and 0.370 inches all transistor **Internal Configuration:** Junction contact all transistor **Electrode Internally-electrically Connected To Case:** Collector all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.200 inches all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 750.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction all transistor **Test Data Document:** 18876-10676180 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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